



LED Display

Product Data Sheet

LTC-5653KF

Spec No.: DS30-2008-0042

Effective Date: 03/21/2008

Revision: -

LITE-ON DCC

RELEASE

LED DISPLAY

LTC-5653KF
DATASHEET

<u>Rev</u>	<u>Description</u>	<u>By</u>
01	ORIGINAL (Refer to contour drawing Revision (-))	<u>KITTISAK</u> <u>Jan 30/2008</u>
<u>(Above data for PD and Customer tracking only)</u>		
-	NPPR Received and Upload on OPNC	<u>KITTISAK</u> <u>Mar 08/2008</u>

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FEATURES

- * 0.56-INCH (14.22-mm) DIGIT HEIGHT.
- * CONTINUOUS UNIFORM SEGMENTS.
- * LOW POWER REQUIREMENT.
- * EXCELLENT CHARACTERS APPEARANCE.
- * HIGH BRIGHTNESS & HIGH CONTRAST.
- * WIDE VIEWING ANGLE.
- * SOLID STATE RELIABILITY.
- * LEAD-FREE PACKAGE (ACCORDING TO ROHS)**

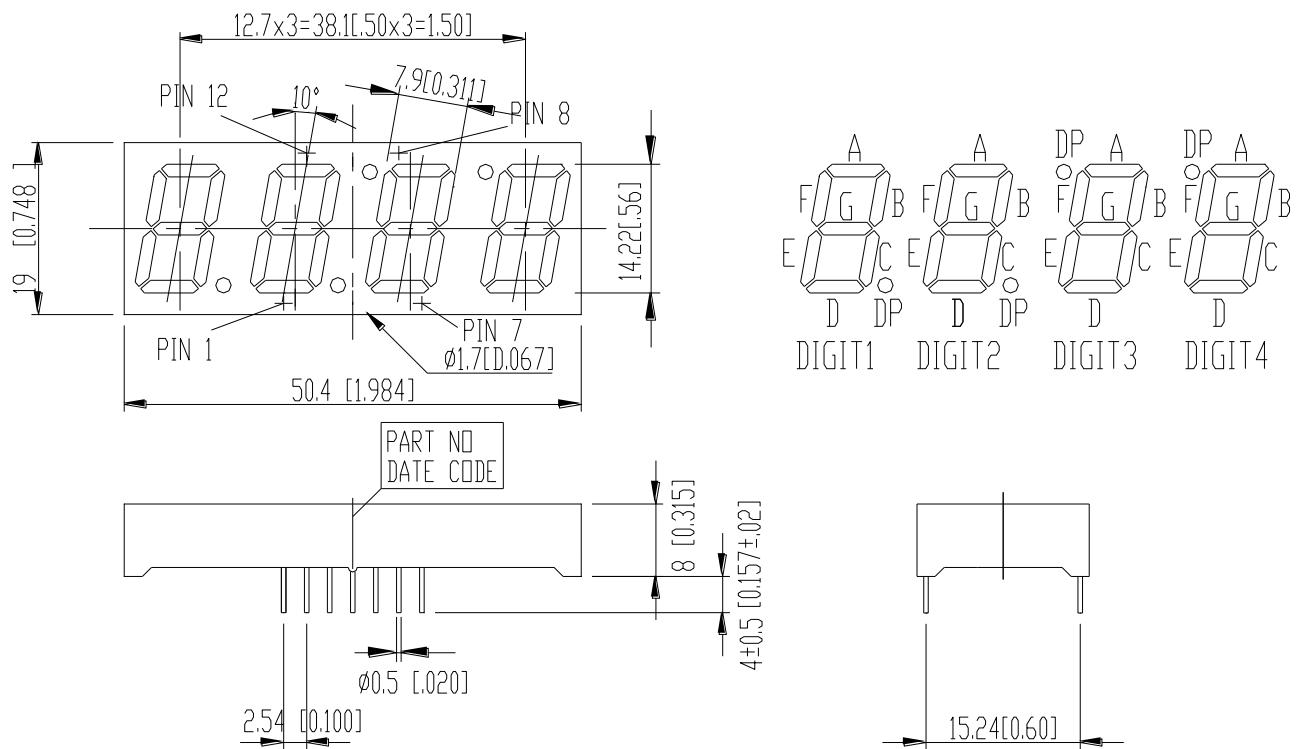
DESCRIPTION

The LTC-5653KF is a 0.56-inch (14.22-mm) digit height quad digit seven-segment display. This device uses AlInGaP Yellow Orange chips (AlInGaP epi on GaAs substrate). The display has gray face and white segments.

DEVICE

PART NO.	DESCRIPTION
AlInGaP Yellow Orange	Common Anode
LTC-5653KF	Rt. Hand Decimal

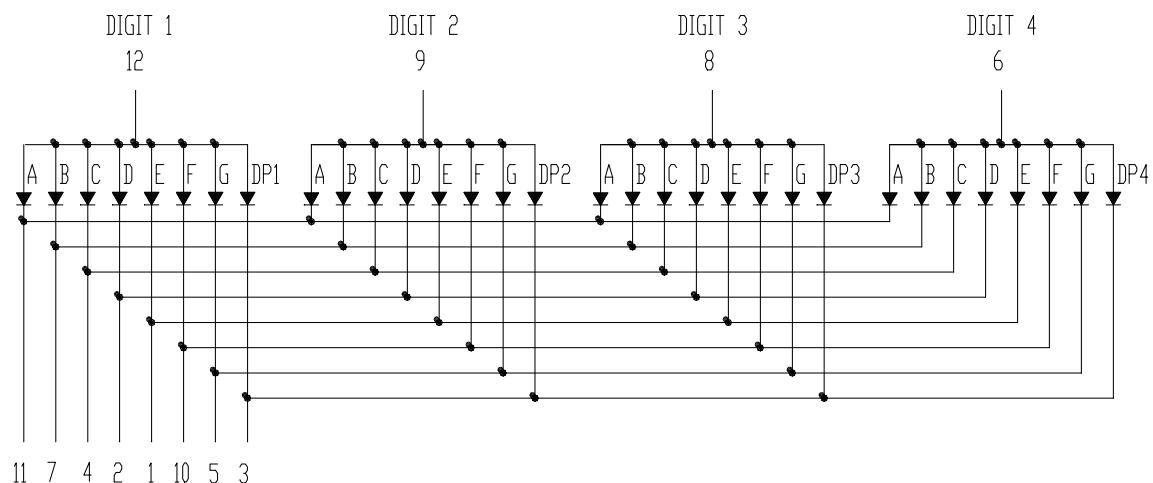
PACKAGE DIMENSIONS



NOTES: 1. All dimensions are in millimeters. Tolerances are $\pm 0.25\text{mm}$ ($0.01''$) unless otherwise noted.

2. Pin tip's shift tolerance is ± 0.4 mm.

INTERNAL CIRCUIT DIAGRAM



PIN CONNECTION

No.	CONNECTION	
1	Cathode	E (Digit 1)
2	Cathode	D (Digit 1)
3	Cathode	D.P. (Digit 1)
4	Cathode	C (Digit 1)
5	Cathode	G (Digit 1)
6	Common	Anode (Digit 4)
7	Cathode	B (Digit 1)
8	Common	Anode (Digit 3)
9	Common	Anode (Digit 2)
10	Cathode	F (Digit 1)
11	Cathode	A (Digit 1)
12	Common	Anode (Digit 1)

ABSOLUTE MAXIMUM RATING AT T_A=25°C

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Segment	70	mW
Peak Forward Current Per Segment (1/10 Duty Cycle, 0.1ms Pulse Width)	90	mA
Continuous Forward Current Per Segment	25	mA
Derating Linear From 25°C Per Segment	0.28	mA/°C
Reverse Voltage Per Segment	5	V
Operating Temperature Range	-35°C to +105°C	
Storage Temperature Range	-35°C to +105°C	
Soldering Conditions: 1/16 inch below seating plane for 3 seconds at 260°C., or temperature of unit (during assembly) not over max. temperature rating above		

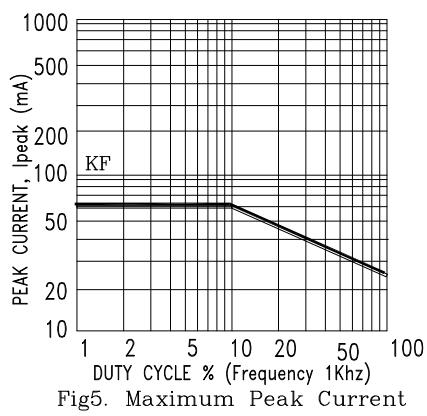
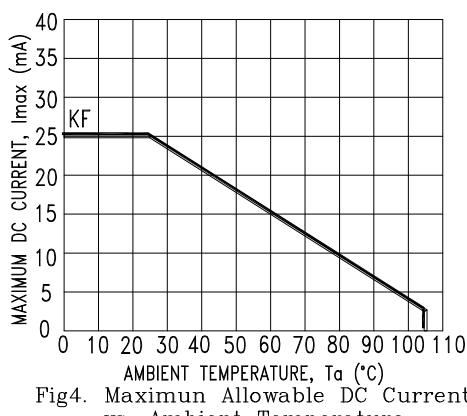
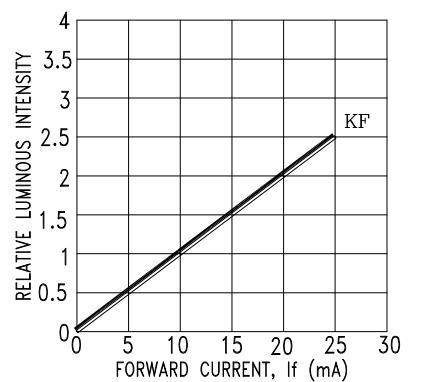
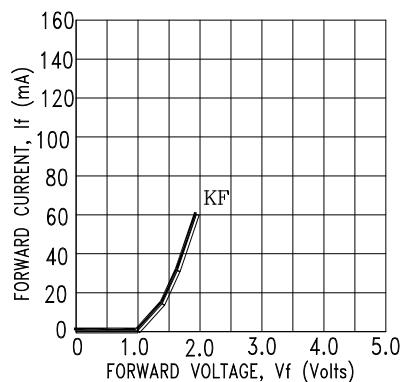
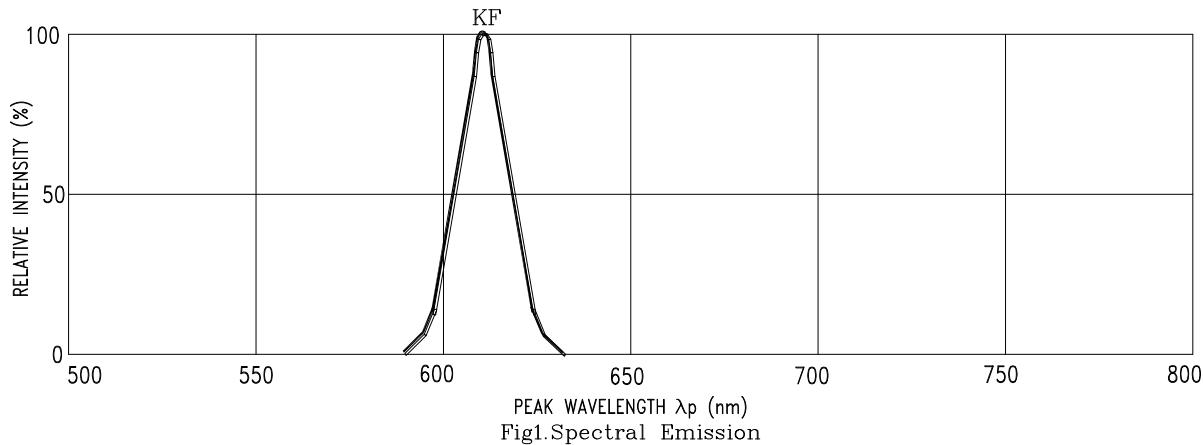
ELECTRICAL / OPTICAL CHARACTERISTICS AT T_A=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I _V	800	2222		μcd	I _F =1mA
Peak Emission Wavelength	λ _P		611		nm	I _F =20mA
Spectral Line Half-Width	Δλ		17		nm	I _F =20mA
Dominant Wavelength	λ _d		605		nm	I _F =20mA
Forward Voltage Per Segment	V _F		2.05	2.6	V	I _F =20mA
Reverse Current Per Segment	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio (Similar Light Area)	I _V -m			2:1		I _F =1mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (commission international DE L'clairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)



NOTE : KF=AlInGaP YELLOW ORANGE